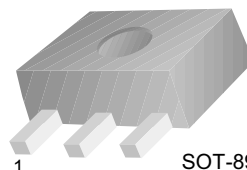


# KSC2982

KSC2982

## Strobe Flash & Medium Power Amplifier

- Excellent  $h_{FE}$  Linearity :  $h_{FE1}=140 \sim 600$
- Low Collector-Emitter Saturation Voltage :  $V_{CE(sat)}=0.5V$
- Collector Dissipation :  $P_C=1\sim 2W$  in Mounted on Ceramic Board



1. Base 2. Collector 3. Emitter

## NPN Epitaxial Silicon Transistor

### Absolute Maximum Ratings $T_a=25^\circ C$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	30	V
$V_{CES}$	Collector-Emitter Voltage	30	V
$V_{CEO}$	Collector-Emitter Voltage	10	V
$V_{EBO}$	Emitter Base Voltage	6	V
$I_C$	Collector Current (DC)	2	A
$I_{CP}$	* Collector Current (Pulse)	4	A
$I_B$	Base Current (DC)	0.4	A
$I_{BP}$	* Base Current (Pulse)	0.8	A
$P_C$	Collector Dissipation	500	mW
$P_C^*$		1,000	mW
$T_J$	Junction Temperature	150	$^\circ C$
$T_{STG}$	Storage Temperature	-55 ~ 150	$^\circ C$

\*  $PW \leq 10ms$ , Duty Cycles  $\leq 30\%$

Mounted on Ceramic Board (250mm<sup>2</sup>x0.8mm)

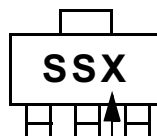
### Electrical Characteristics $T_a=25^\circ C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C=10mA$ , $I_B=0$	10			V
$BV_{EBO}$	Emitter-Base Breakdown Voltage	$I_E=1mA$ , $I_C=0$	6			V
$I_{CBO}$	Collector Cut-off Current	$V_{CB}=30V$ , $I_E=0$			100	nA
$I_{EBO}$	Emitter Cut-off Current	$V_{BE}=6V$ , $I_C=0$			100	nA
$h_{FE1}$ $h_{FE2}$	DC Current Gain	$V_{CE}=1V$ , $I_C=0.5A$ $V_{CE}=1V$ , $I_C=2A$	140 70	140	600	nA
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=2A$ , $I_B=50mA$		0.2	0.5	V
$V_{BE(on)}$	Base-Emitter On Voltage	$V_{CE}=1V$ , $I_C=2A$		0.86	1.5	V
$f_T$	Current Gain Bandwidth Product	$V_{CE}=1V$ , $I_C=2A$		150		MHz
$C_{ob}$	Output Capacitance	$V_{CB}=10V$ , $I_E=0$ , $f=1MHz$		27		pF

### $h_{FE1}$ Classification

Classification	A	B	C	D
$h_{FE1}$	140 ~ 240	200 ~ 330	300 ~ 450	420 ~ 600

Marking



$h_{FE}$  grade

# Typical Characteristics

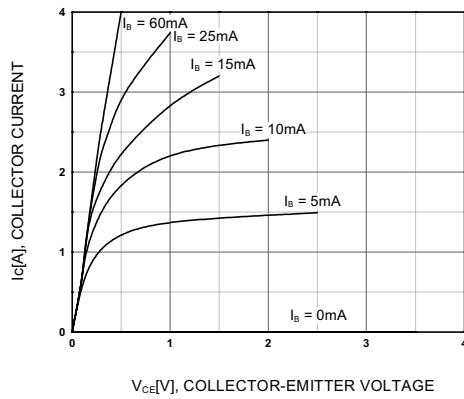


Figure 1. Static Characteristic

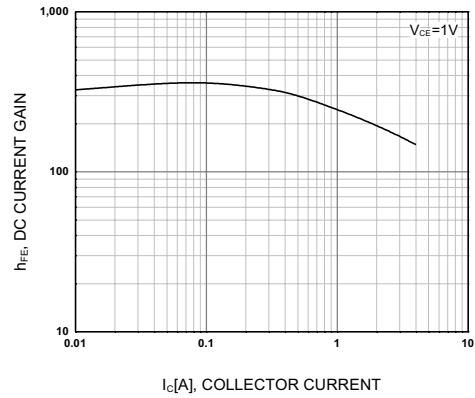


Figure 2. DC current Gain

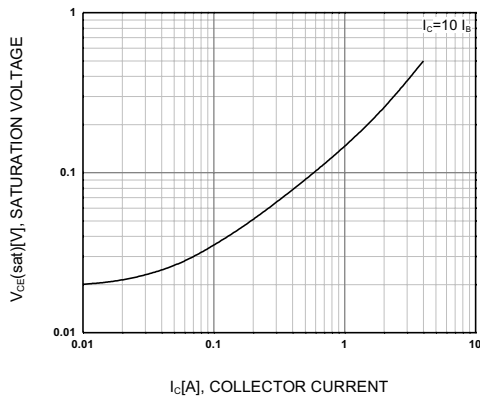


Figure 3. Collector-Emitter Saturation Voltage

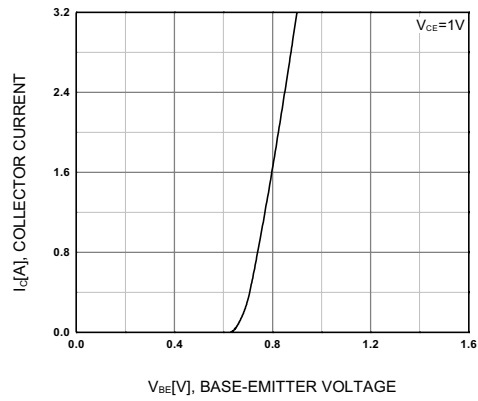


Figure 4. Base-Emitter On Voltage

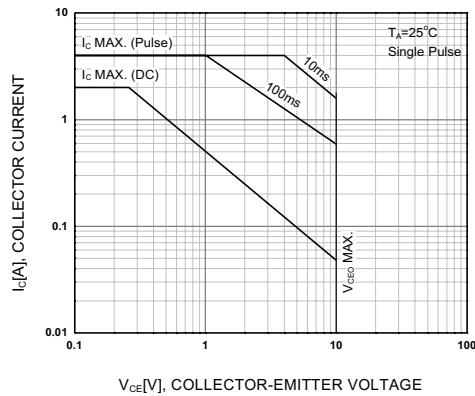


Figure 5. Safe Operating Area

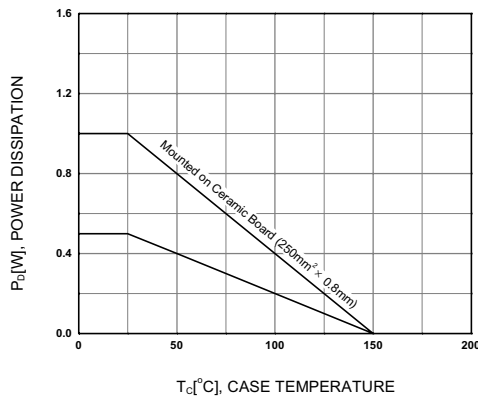
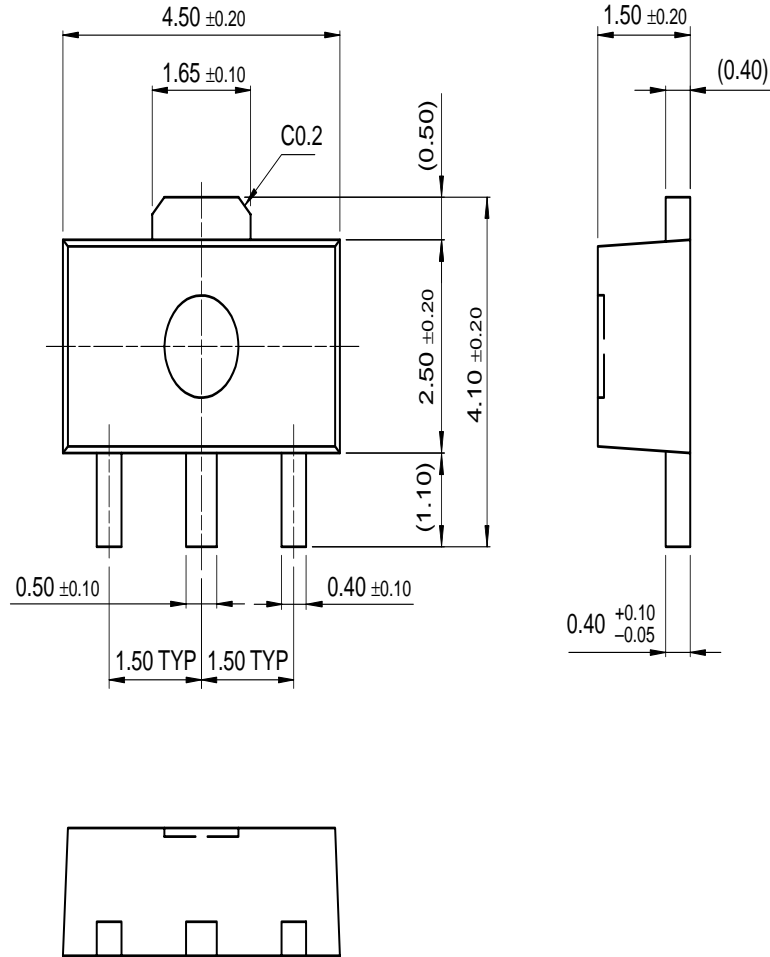


Figure 6. Power Derating

# Package Dimensions

## SOT-89



Dimensions in Millimeters

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